

Fixed Attenuator Chip

- ♦ DC to 18 GHz
- ◆ 3 dB
- ◆ 200mW

Features

- Thin film
- High attenuation accuracy
- Small VSWR
- Ceramic chip: 99% alumina
- Laser trimmed
- Low cost-high performance

Model No. Description

FACXXXXX

___x - Soldering method A or B

XX- attenuation: **dB.

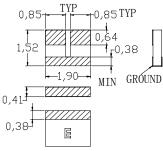
XX- frequency range 06: DC to 6GHz

10: DC to 10GHz 12: DC to 12.4GHz 18: DC to 18GHz 26: DC to 26.5GHz.

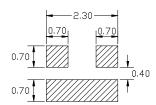
Soldering method A:The gold terminals in this series are just designed to use wire-boning application.

Soldering method B:The gold terminals in this series are just designed to use lead free reflow application.

Package Outlines



Recommended Layout



Note: all dimensions shown in mm

Specifications

Frequency Range DC to 18 GHz

Attenuation 3 dB Attenuation Accuracy (Typical.)

> ±0.5 dB DC to 4 GHz + 0.5 dB 4 to 8 GHz + 0.5 dB 8 to 12.4 GHz + 1.0 dB 12.4 to 18 GHz

Attenuation Stability 0.0001 dB/dB/°C

Nominal Impedance 50 Ohm Rated Input Power 200mW

Operating Temperature -55 °C to +150 °C

FREQ. RANGE (GHz)	VSWR(:1) Typical
DC to 4	1.05
4 to 8	1.10
8 to 12.4	1.15
12.4 to 18	1.40

Material Specification

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substrate	99% alumina
terminal	Gold over Tiw
	Gold thickness: 3 µ m
resistor	Tantalum nitride thin film

Average Power Derating Curve

